

DIP4, DC Input, Photo Transistor Coupler**Description**

The TWS851 series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon planar high voltage phototransistor detector in a plastic DIP4 package with different lead forming options.

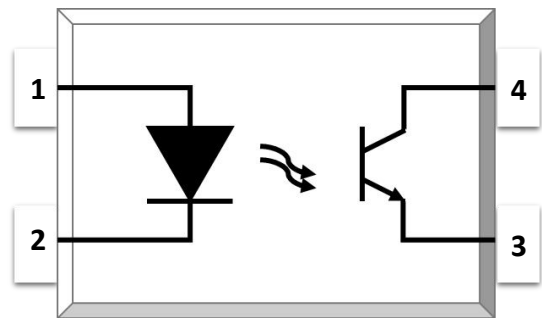
With the robust coplanar double mold structure, TWS851 series provide the most stable isolation feature.

Features

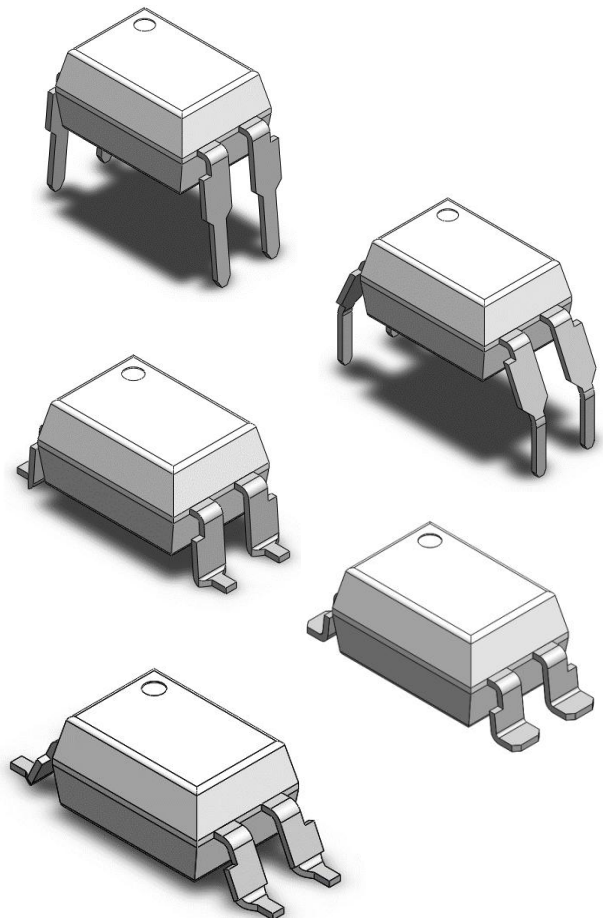
- High isolation 5000 VRMS
- DC input with transistor output
- Operating temperature range - 55 °C to 110 °C
- REACH compliance
- Halogen free
- MSL class 1

Applications

- Switch mode power supplies
- Programmable controllers
- Household appliances
- Office equipment

SCHEMATIC**PIN DEFINITION**

1. Anode
2. Cathode
3. Emitter
4. Collector

PACKAGE OUTLINE

DIP4, DC Input, Photo Transistor Coupler**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT	NOTE
INPUT				
Forward Current	I_F	60	mA	
Peak Forward Current	I_{FP}	1	A	1
Reverse Voltage	V_R	6	V	
Input Power Dissipation	P_I	100	mW	
OUTPUT				
Collector - Emitter Voltage	V_{CEO}	350	V	
Emitter - Collector Voltage	V_{ECO}	7	V	
Collector Current	I_C	50	mA	
Output Power Dissipation	P_O	150	mW	
COMMON				
Total Power Dissipation	P_{tot}	200	mW	
Isolation Voltage	V_{iso}	5000	V _{rms}	2
Operating Temperature	T_{opr}	-55~110	°C	
Storage Temperature	T_{stg}	-55~150	°C	
Soldering Temperature	T_{sol}	260	°C	

Note 1. 100μs pulse, 100Hz frequency

Note 2. AC For 1 Minute, R.H. = 40 ~ 60%

DIP4, DC Input, Photo Transistor Coupler

ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C							
PARAMETER	SYMBOL	MIN	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
INPUT							
Forward Voltage	V_F	-	1.24	1.4	V	$I_F=10\text{mA}$	
Reverse Current	I_R	-	-	10	μA	$V_R=6\text{V}$	
Input Capacitance	C_{in}	-	10	-	pF	$V=0, f=1\text{kHz}$	
OUTPUT							
Collector Dark Current	I_{CEO}	-	-	100	nA	$V_{CE}=200\text{V}, I_F=0$	
Collector-Emitter Breakdown Voltage	BV_{CEO}	350	-	-	V	$I_C=0.1\text{mA}, I_F=0$	
Emitter-Collector Breakdown Voltage	BV_{ECO}	7	-	-	V	$I_E=0.1\text{mA}, I_F=0$	
TRANSFER CHARACTERISTICS							
Current Transfer Ratio	TWS851	CTR	50	-	600	%	$I_F=5\text{mA}, V_{CE}=5\text{V}$
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	-	0.055	0.4	V	$I_F=20\text{mA}, I_C=1\text{mA}$
Isolation Resistance		R_{ISO}	10^{12}	10^{14}	-	Ω	DC500V, 40 ~ 60% R.H.
Floating Capacitance		C_{IO}	-	0.6	1	pF	$V=0, f=1\text{MHz}$
Response Time (Rise)		t_r	-	2	18	μs	$V_{CE}=2\text{V}, I_C=2\text{mA}$ 3
Response Time (Fall)		t_f	-	4	18	μs	$R_L=100\Omega$ 3
Cut-off Frequency		f_c	-	80	-	kHz	$V_{CE}=2\text{V}, I_C=2\text{mA}$ $R_L=100\Omega, -3\text{dB}$ 4

Note 3. Fig.11&12

Note 4. Fig.13

CHARACTERISTIC CURVES

Fig.1 Forward Current vs. Ambient Temperature

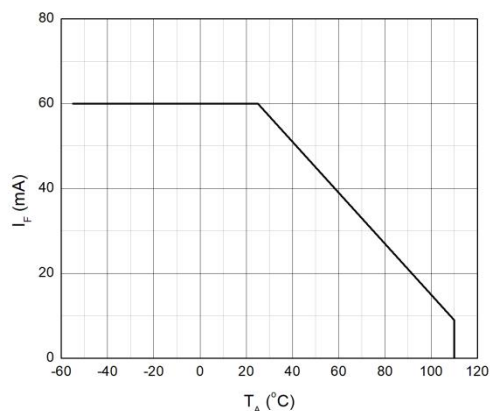


Fig.2 Collector Power Dissipation vs. Ambient Temperature

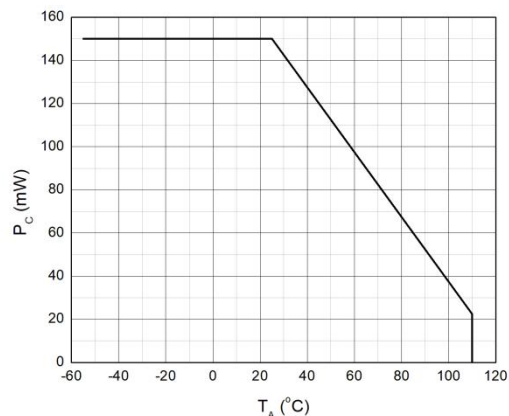


Fig.3 Forward Current vs. Forward Voltage

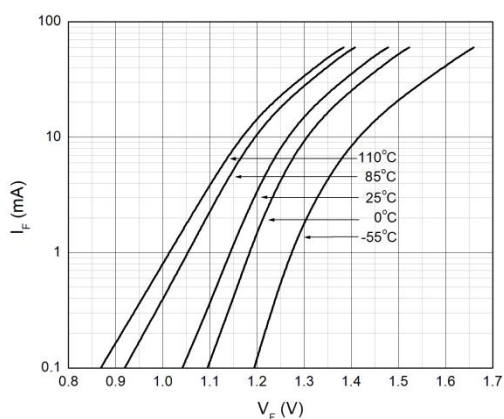


Fig.4 Collector Dark Current vs. Ambient Temperature

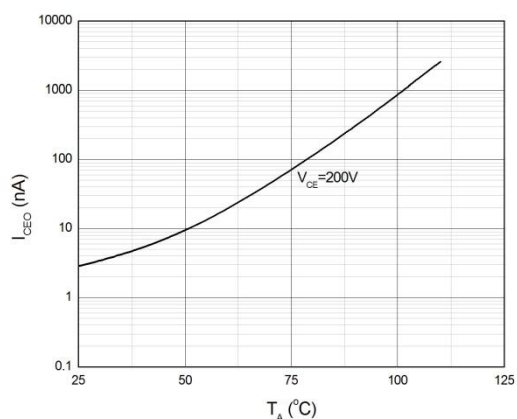


Fig.5 Collector Current vs. Collector-emitter Voltage

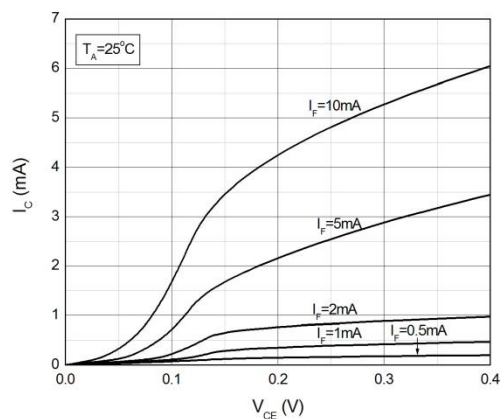
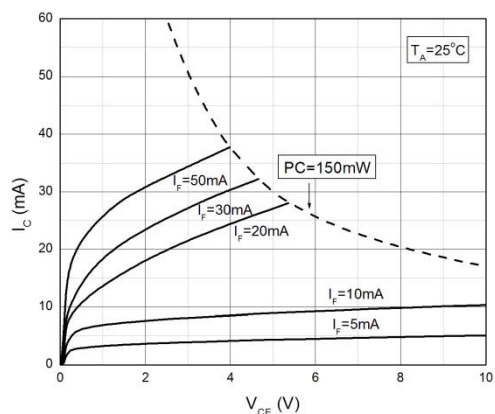


Fig.6 Collector Current vs. Collector-emitter Voltage



CHARACTERISTIC CURVES

Fig.7 Normalized Current Transfer Ratio vs. Forward Current

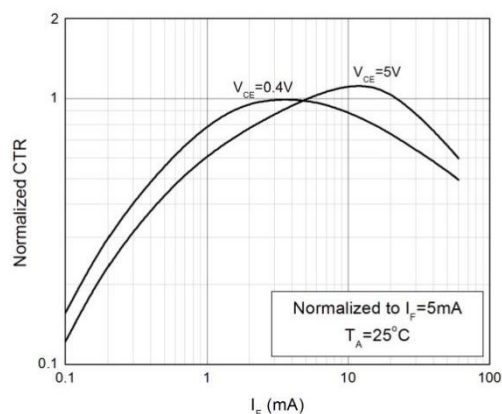


Fig.8 Normalized Current Transfer Ratio vs. Ambient Temperature

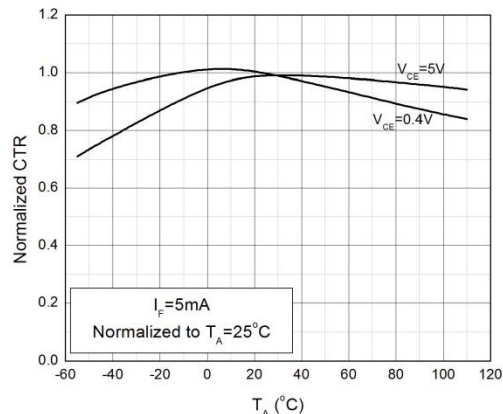


Fig.9 Collector-emitter Saturation Voltage vs. Ambient Temperature

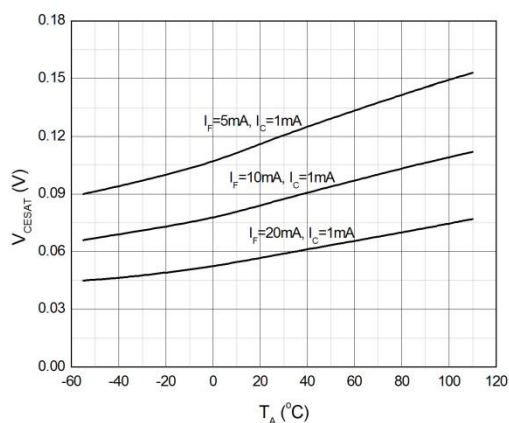


Fig.10 Switching Time vs. Load Resistance

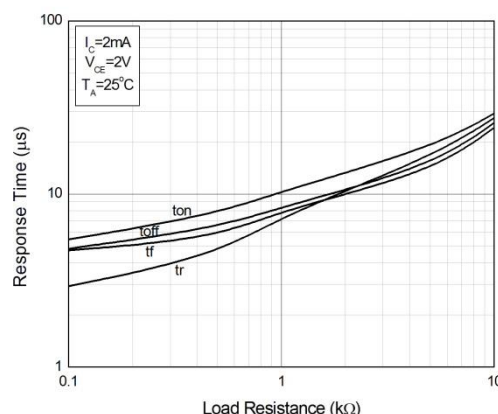
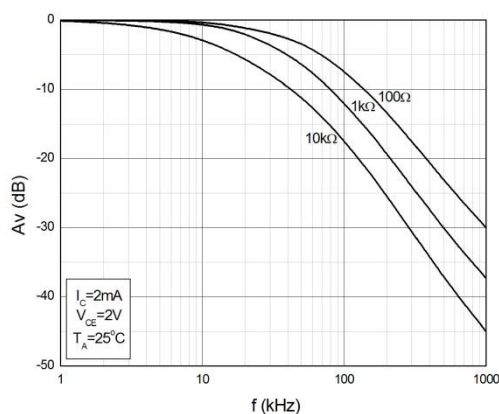


Fig.11 Frequency Response



TEST CIRCUITS

Fig.12 Test Circuits of Response Time

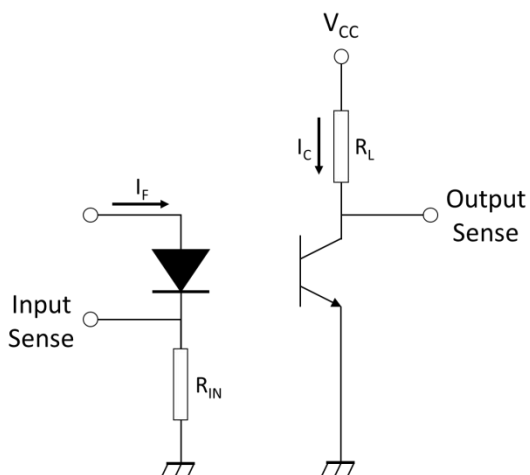


Fig.13 Curves of Response Time

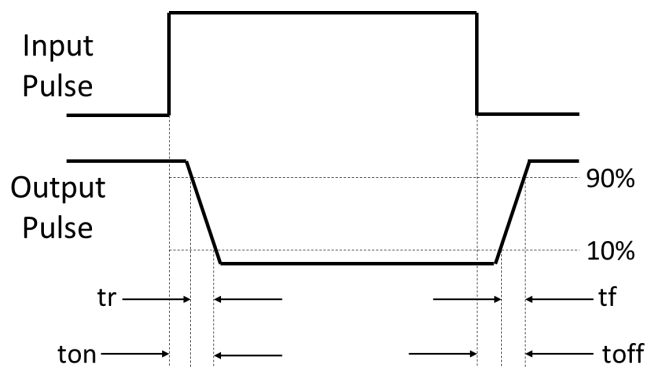
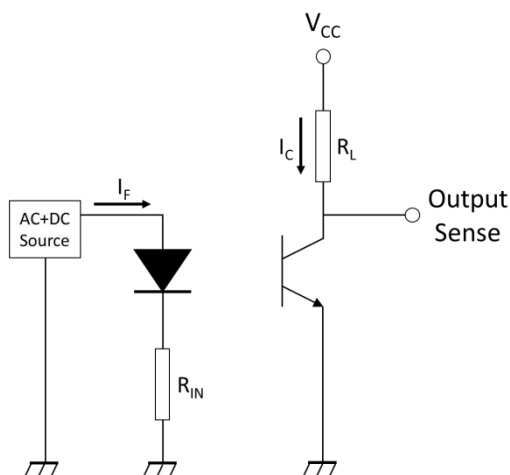
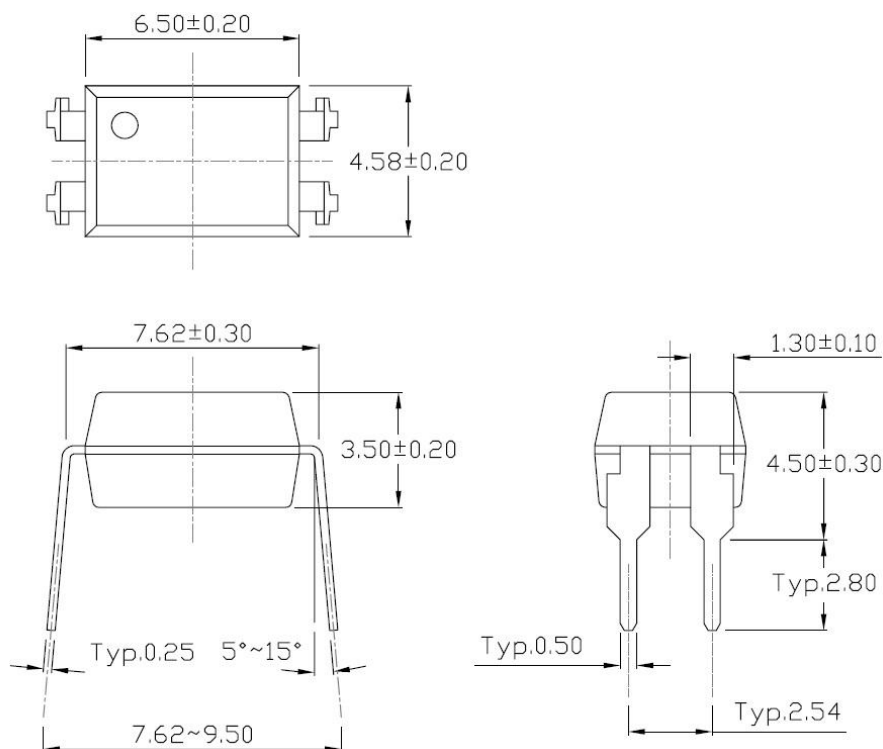
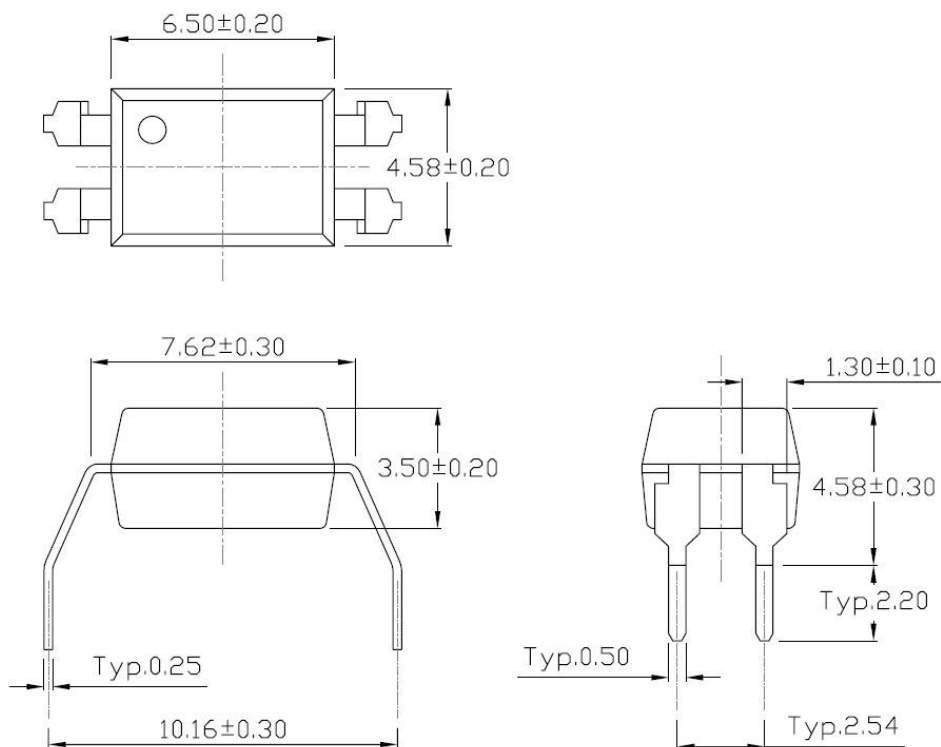
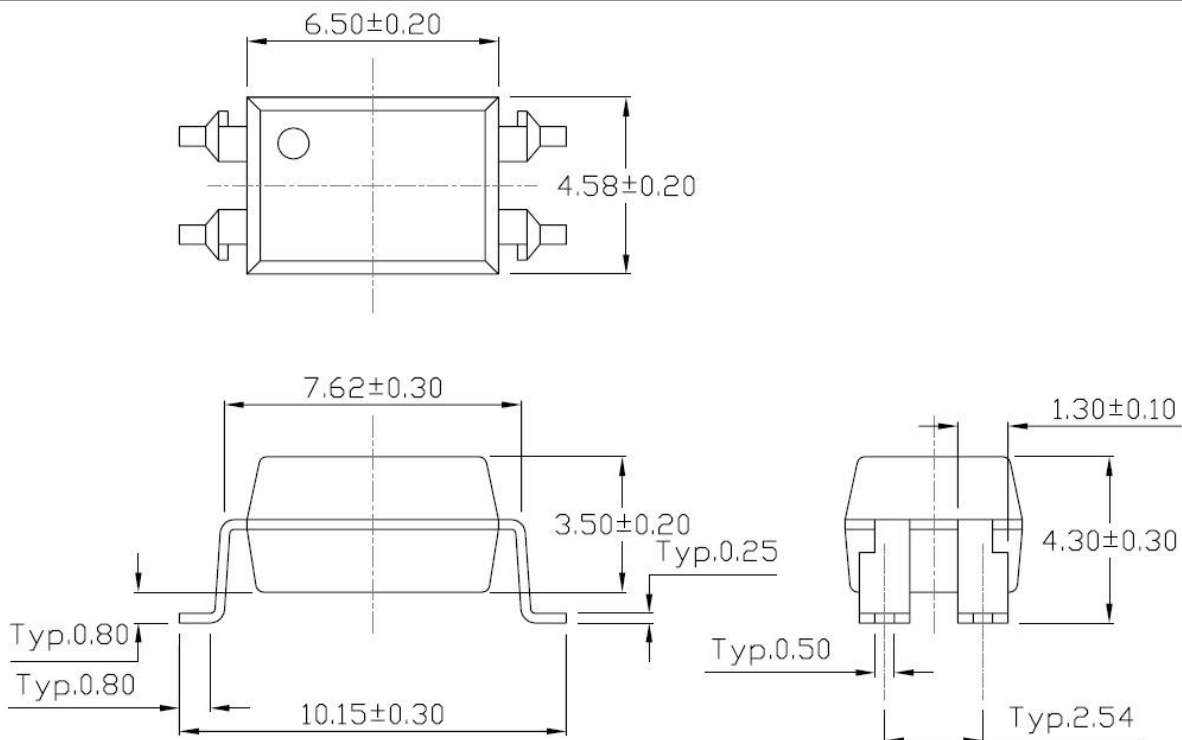
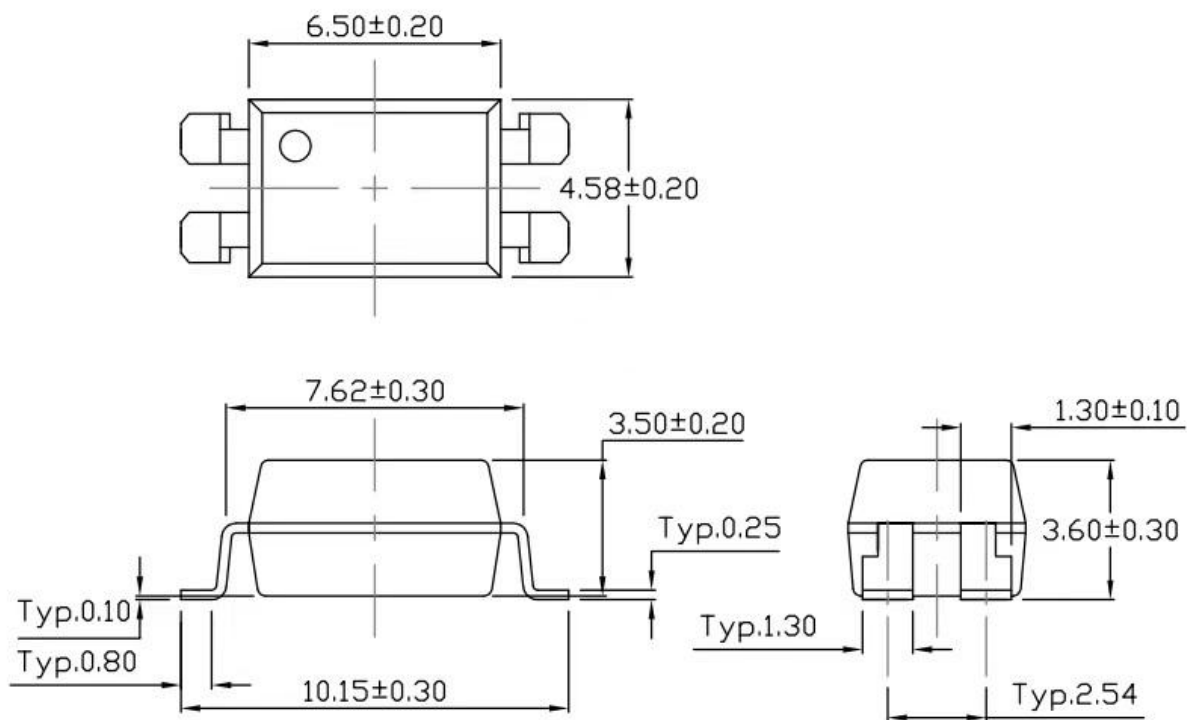
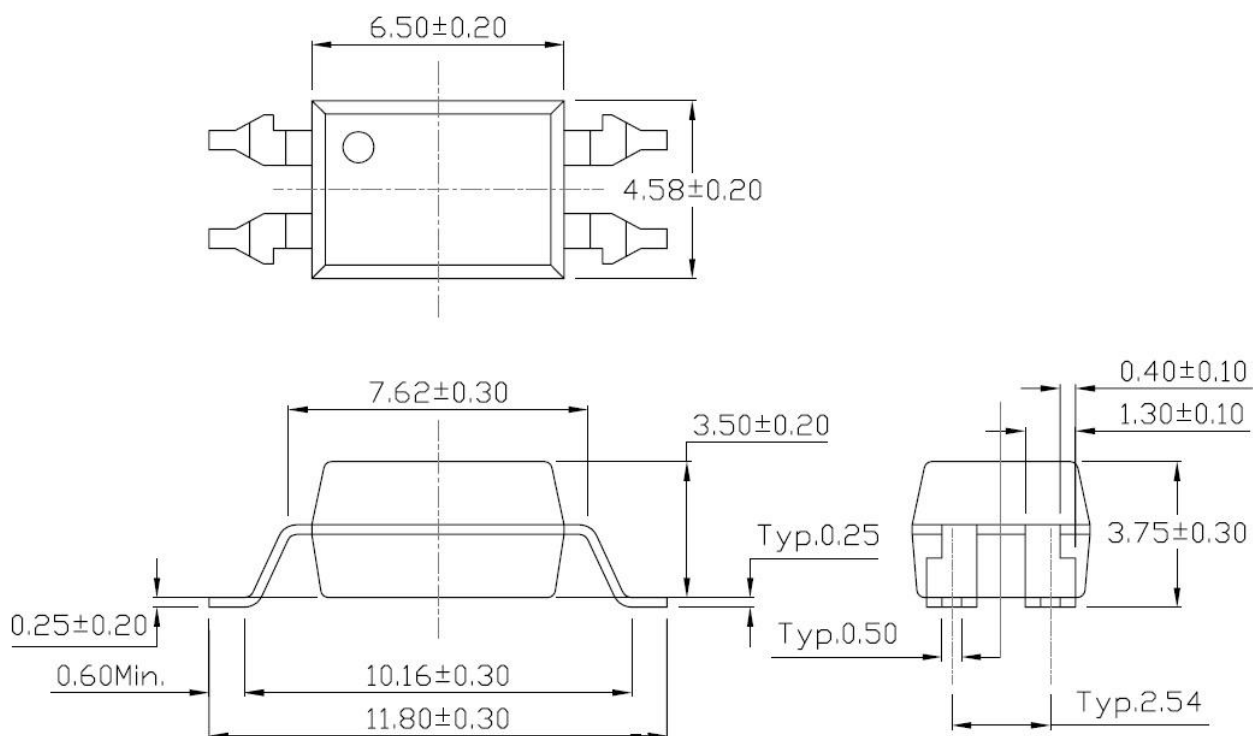
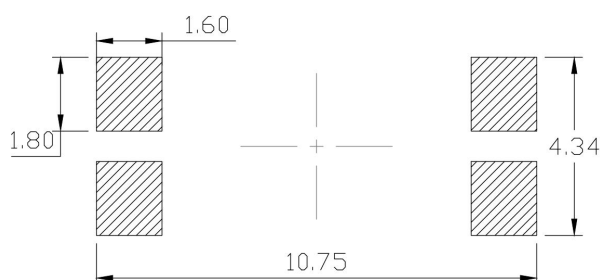
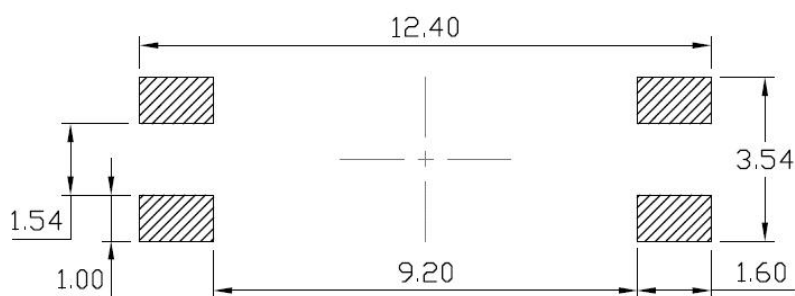


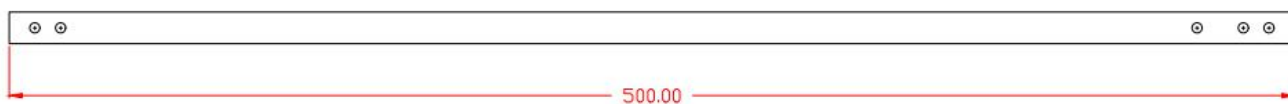
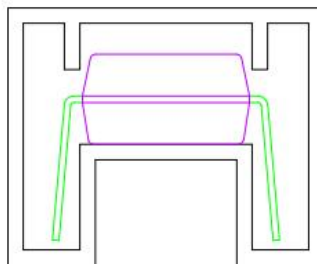
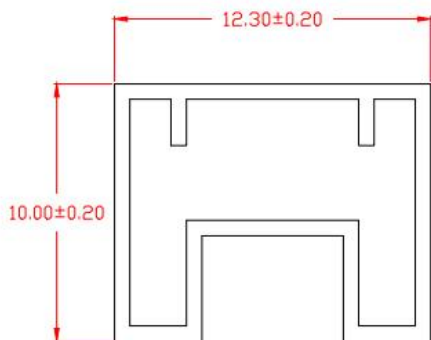
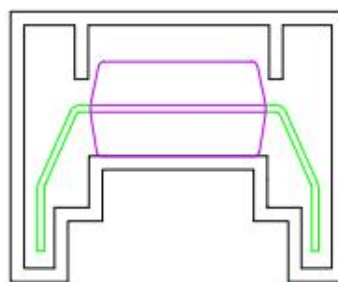
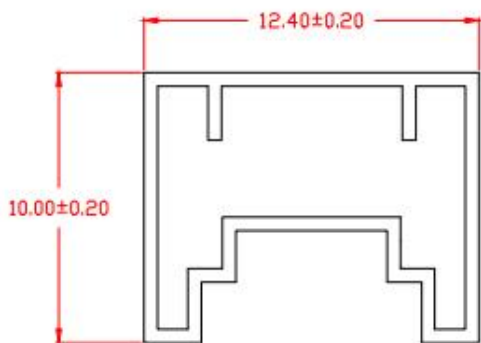
Fig.14 Test Circuits of Frequency Response



DIP4, DC Input, Photo Transistor Coupler**PACKAGE DIMENSIONS** (Dimensions in mm unless otherwise stated)**Standard DIP – Through Hole (DIP Type)****Gullwing (400mil) Lead Forming – Through Hole (M Type)**

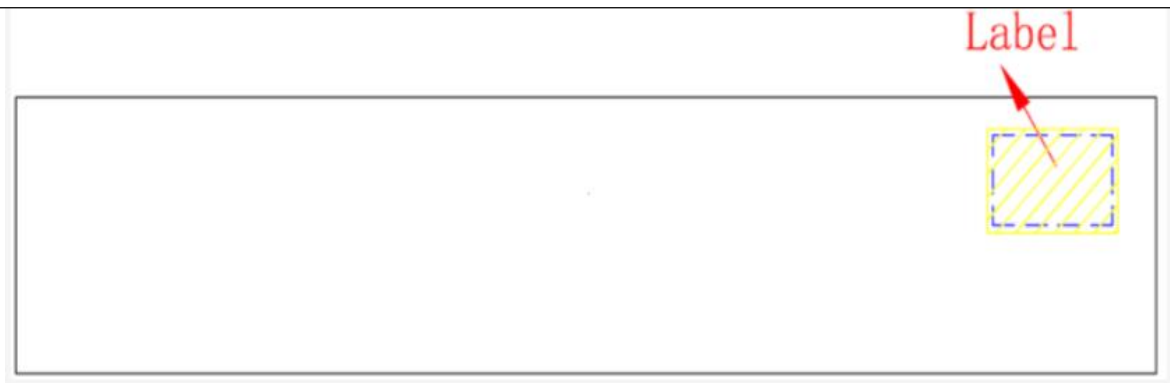
DIP4, DC Input, Photo Transistor Coupler**PACKAGE DIMENSIONS** (Dimensions in mm unless otherwise stated)**Surface Mount Lead Forming (S Type)****Surface Mount (Low Profile) Lead Forming (SL Type)**

PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)**Surface Mount (Gullwing) Lead Forming (SLM Type)****RECOMMENDED SOLDER MASK** (Dimensions in mm unless otherwise stated)**Surface Mount Lead Forming & Surface Mount (Low Profile) Lead Forming****Surface Mount (Gullwing) Lead Forming**

TUBE SPECIFICATIONS (Dimensions in mm unless otherwise stated)**Standard DIP****Standard M**

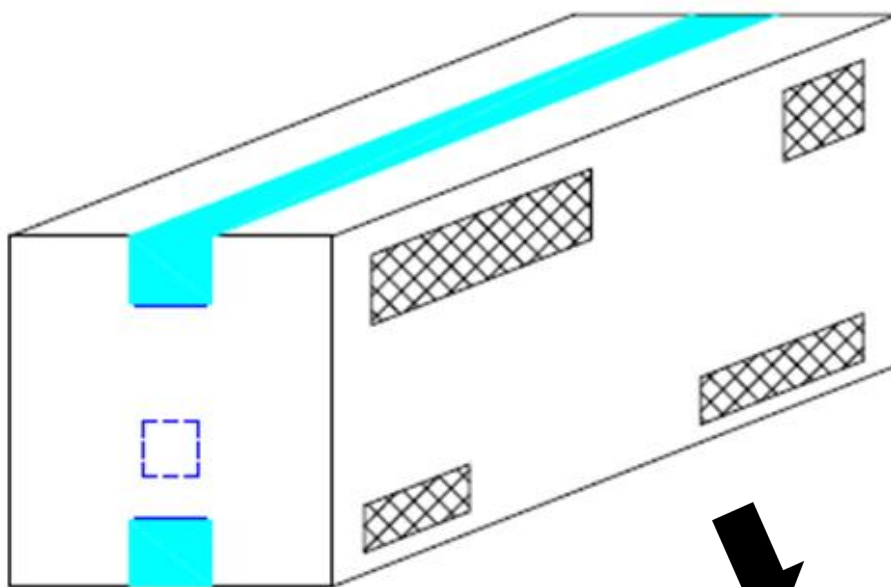
BOX SPECIFICATIONS (Tube Type)

Inner Box



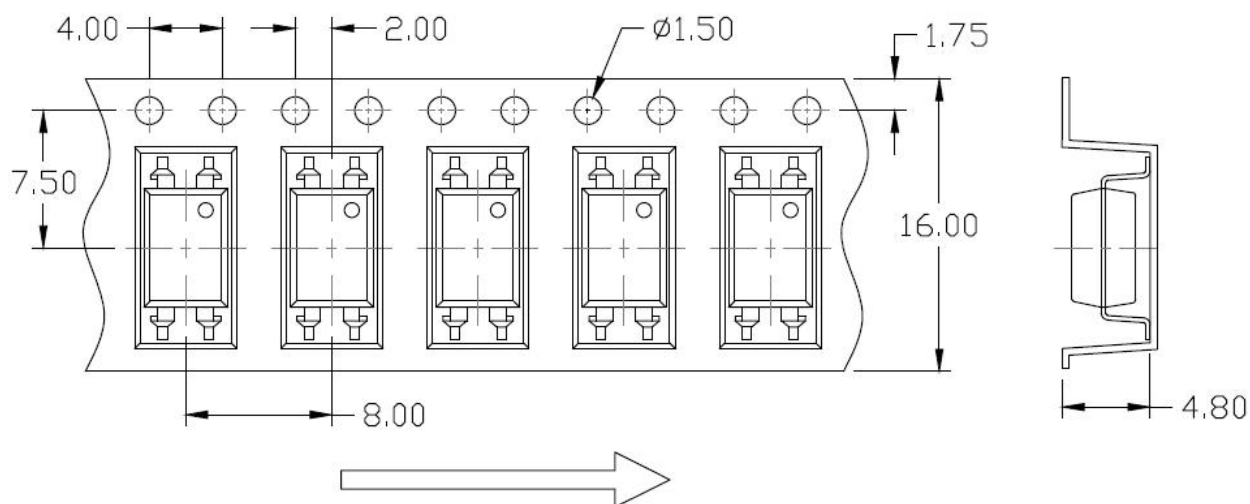
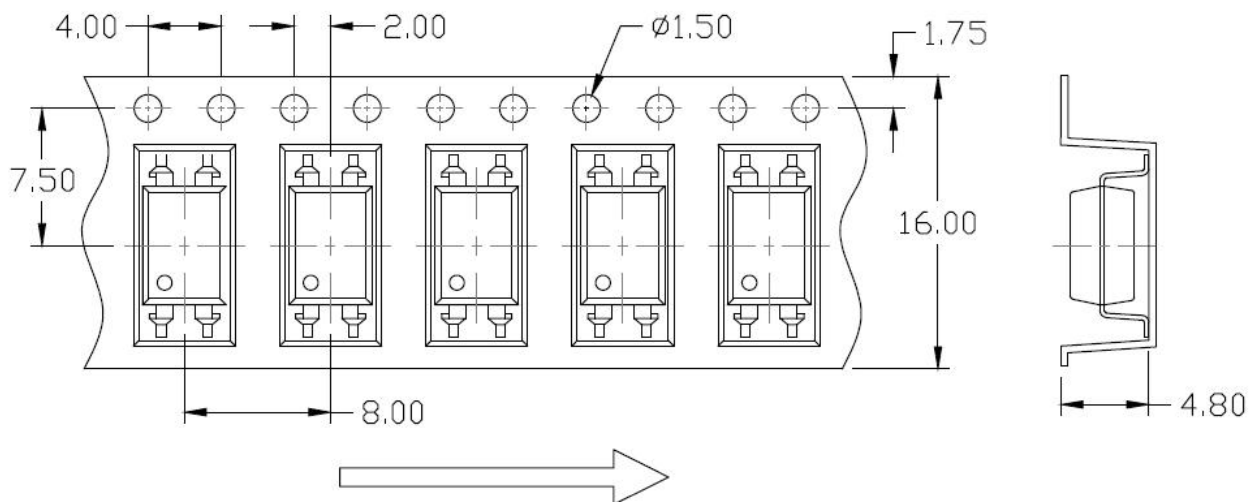
L x W x H = 52.5cm x 10.7cm x 4.7cm

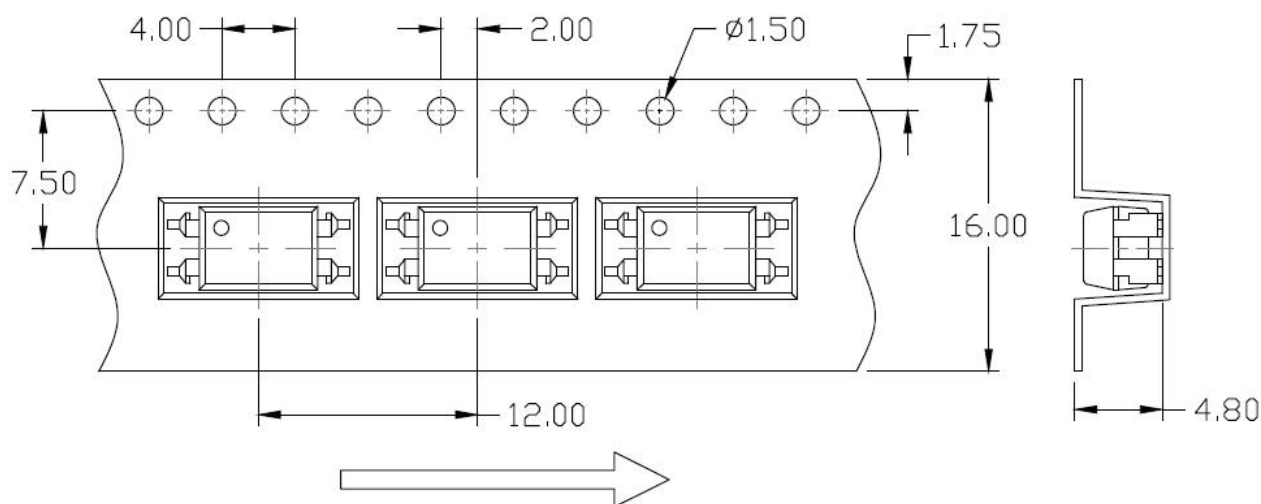
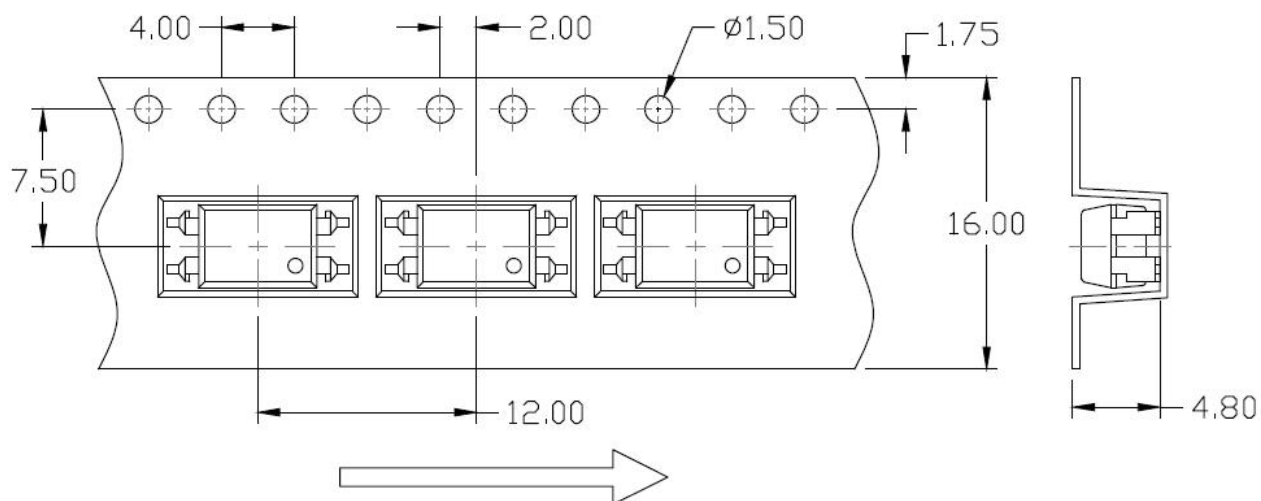
Outer Box

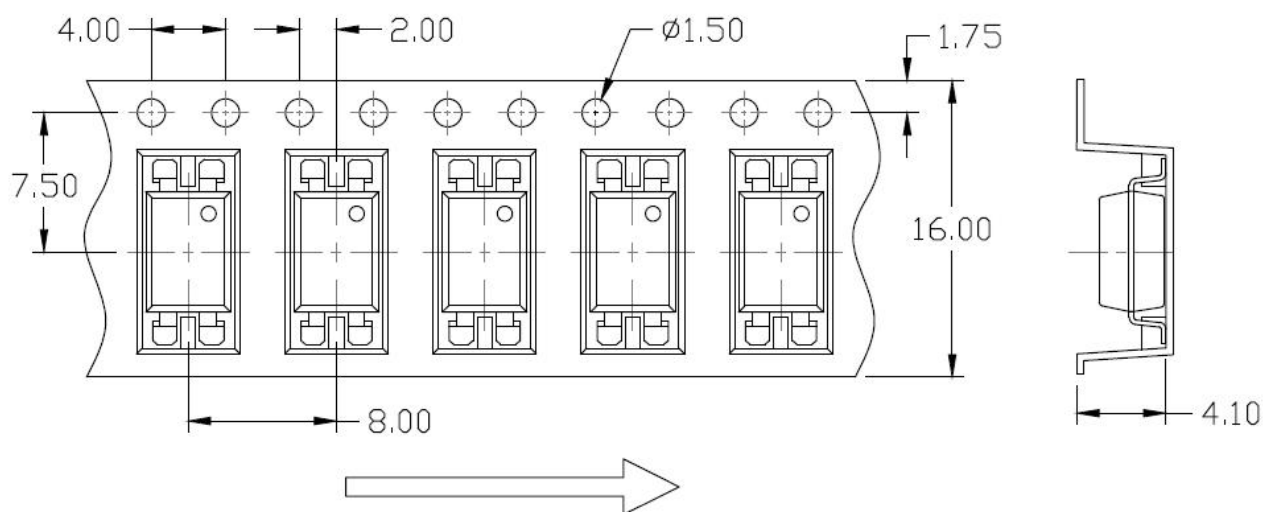
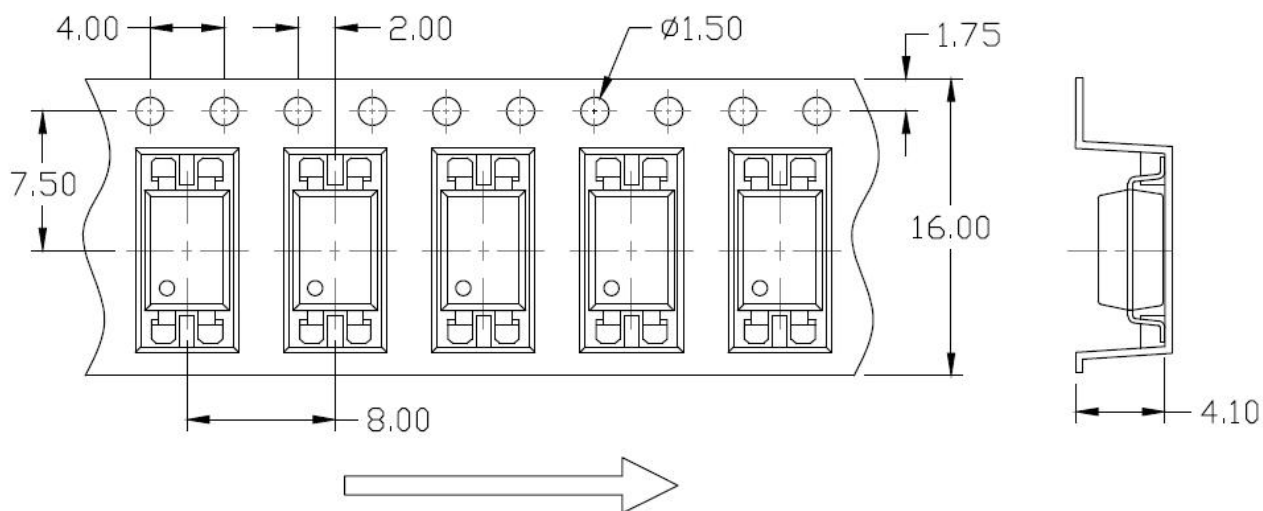


L x W x H = 53.5cm x 23.5cm x 25.5cm



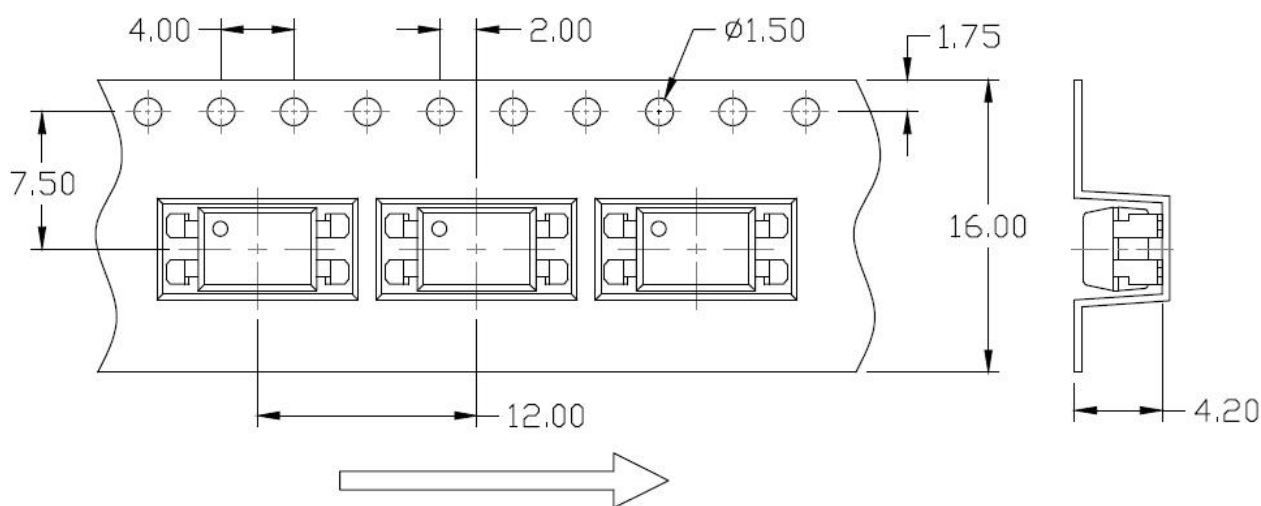
CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)**Option S(T1)****Option S(T2)**

CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)**Option S(T3)****Option S(T4)**

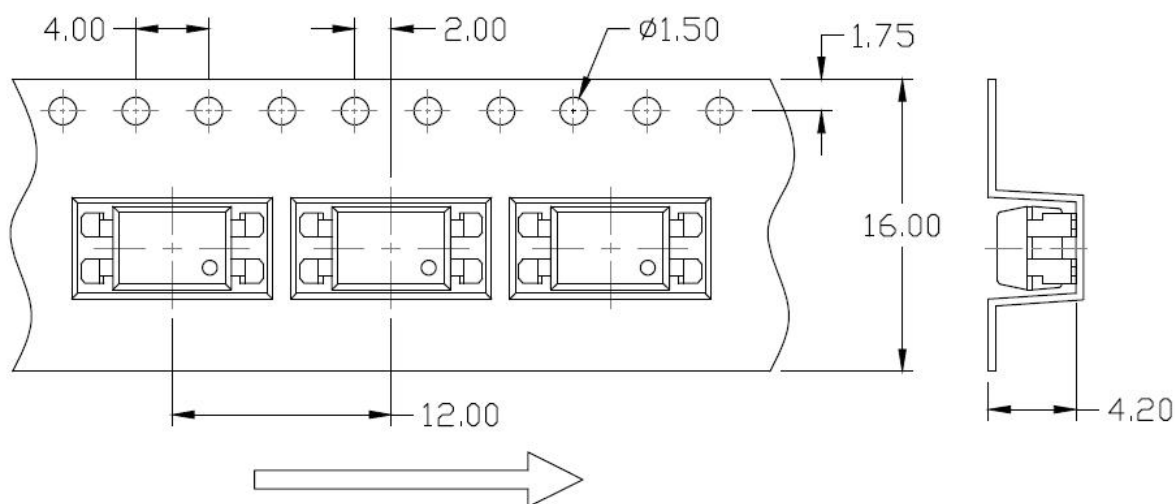
CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)**Option SL(T1)****Option SL(T2)**

CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option SL(T3)

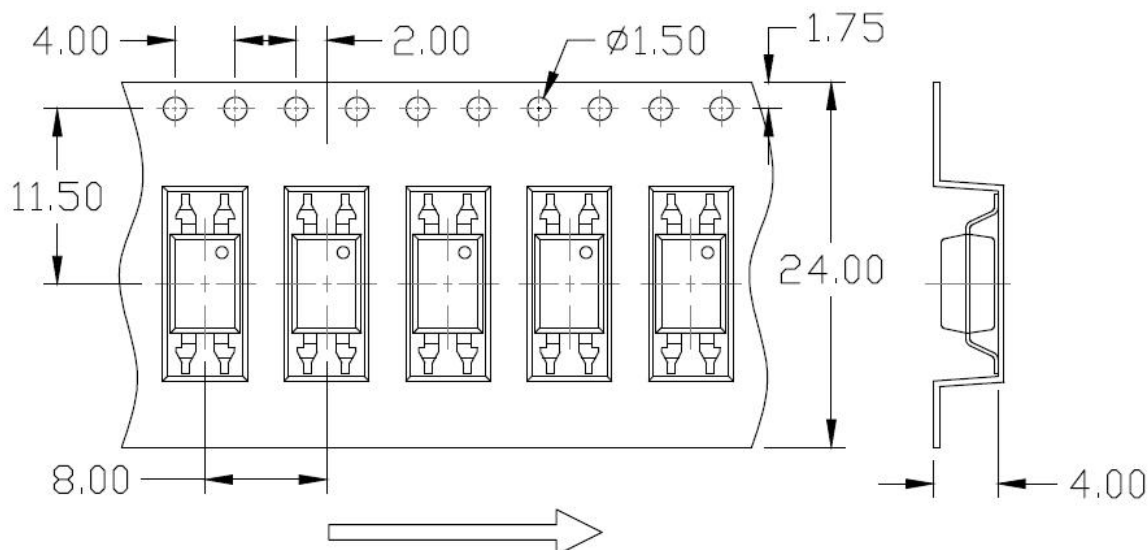


Option SL(T4)

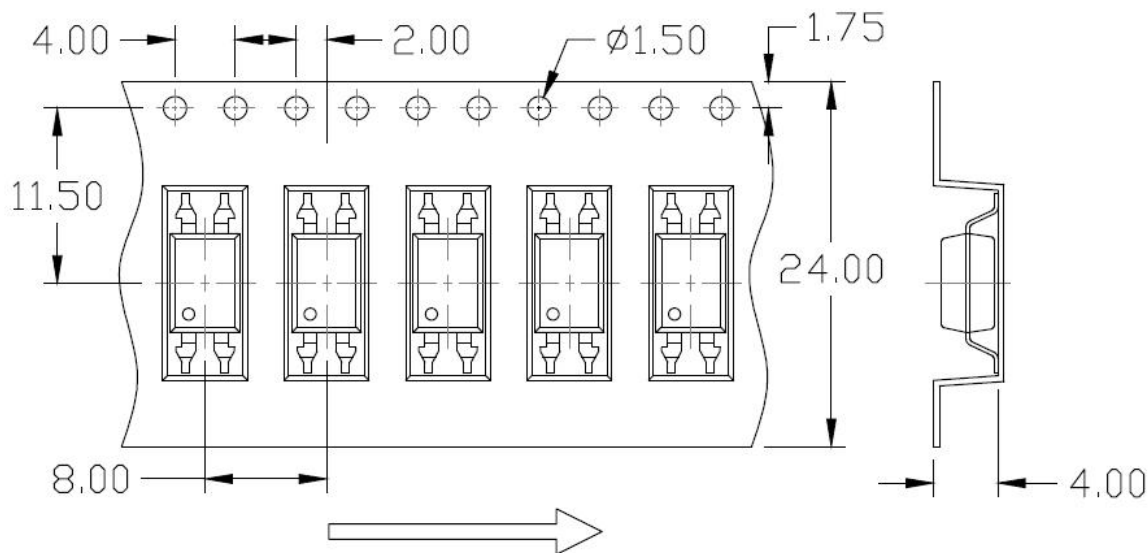


CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option SLM(T1)

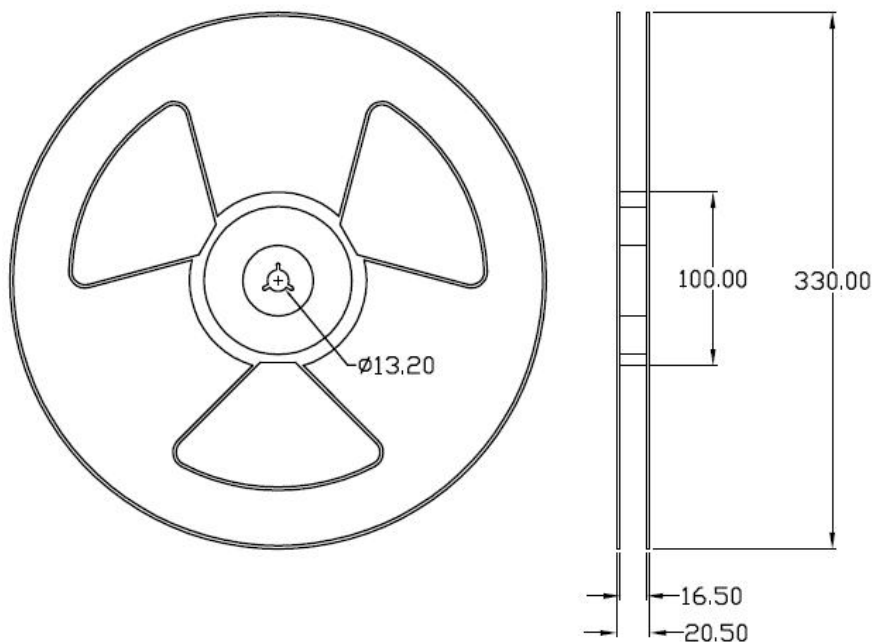


Option SLM(T2)

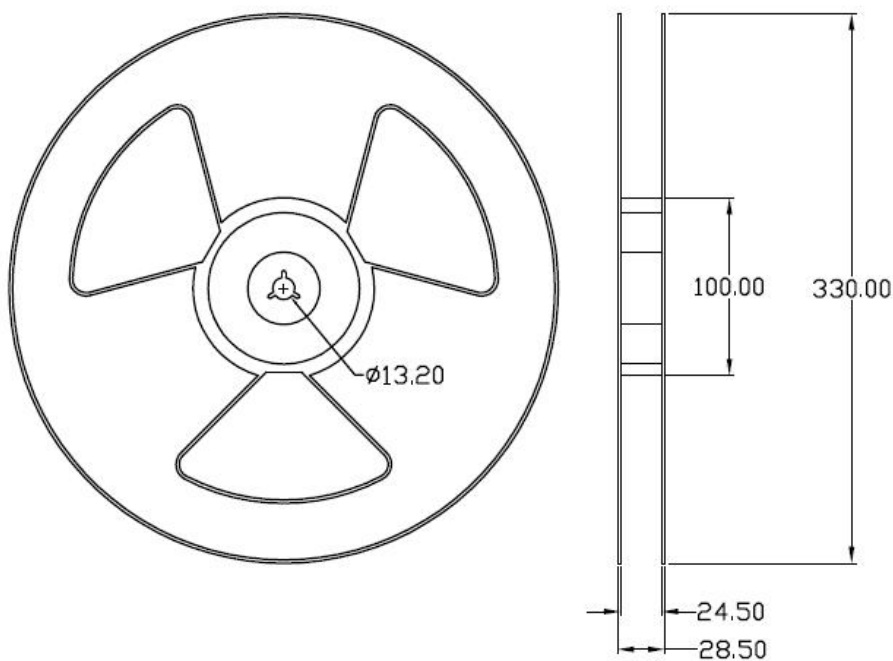


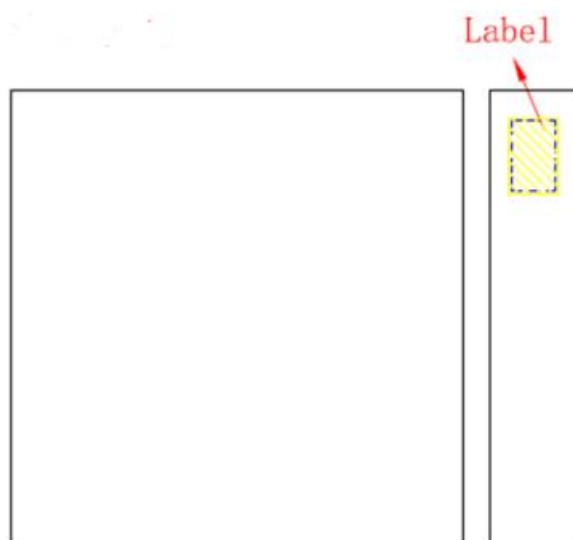
REEL SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option S & Option SL

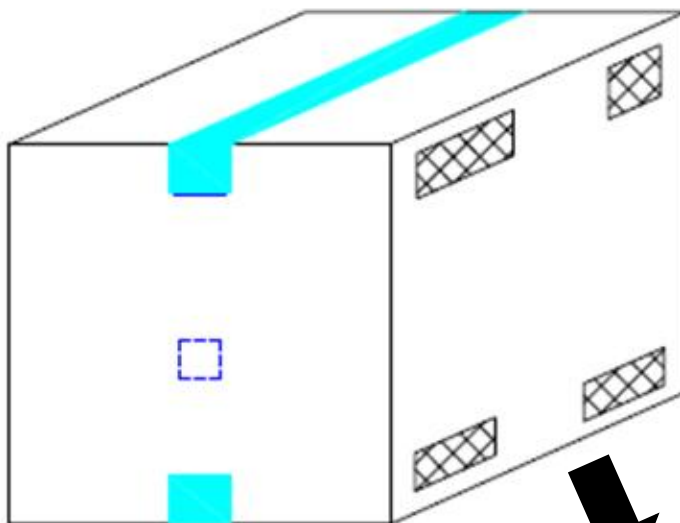


Option SLM

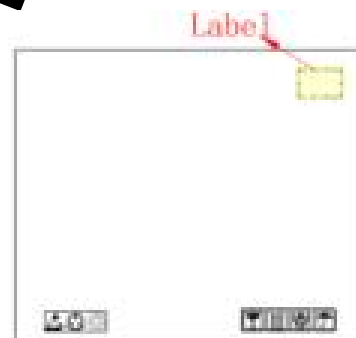


BOX SPECIFICATIONS (Reel Type)**Inner Box**

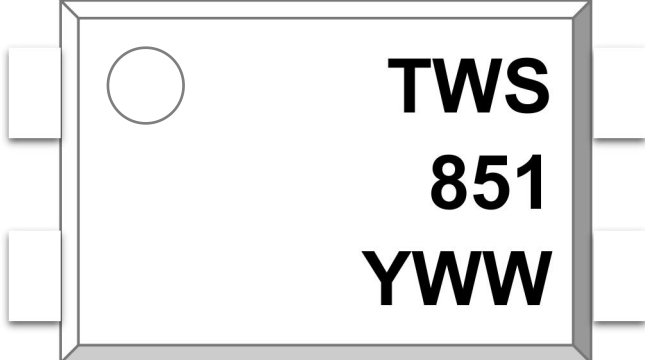
- L x W x H = 36cm x 36cm x 6.9cm

Outer Box

- Option1: L x W x H = 45cm x 38cm x 38cm
- Option2: L x W x H = 39cm x 38cm x 38cm



ORDERING AND MARKING INFORMATION**MARKING INFORMATION**

	TWS : Company Abbr. 851 : Part Number & Rank Y : Fiscal Year WW : Work Week
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ORDERING INFORMATION**LABEL INFORMATION****TWS851(Y)(Z)-G**

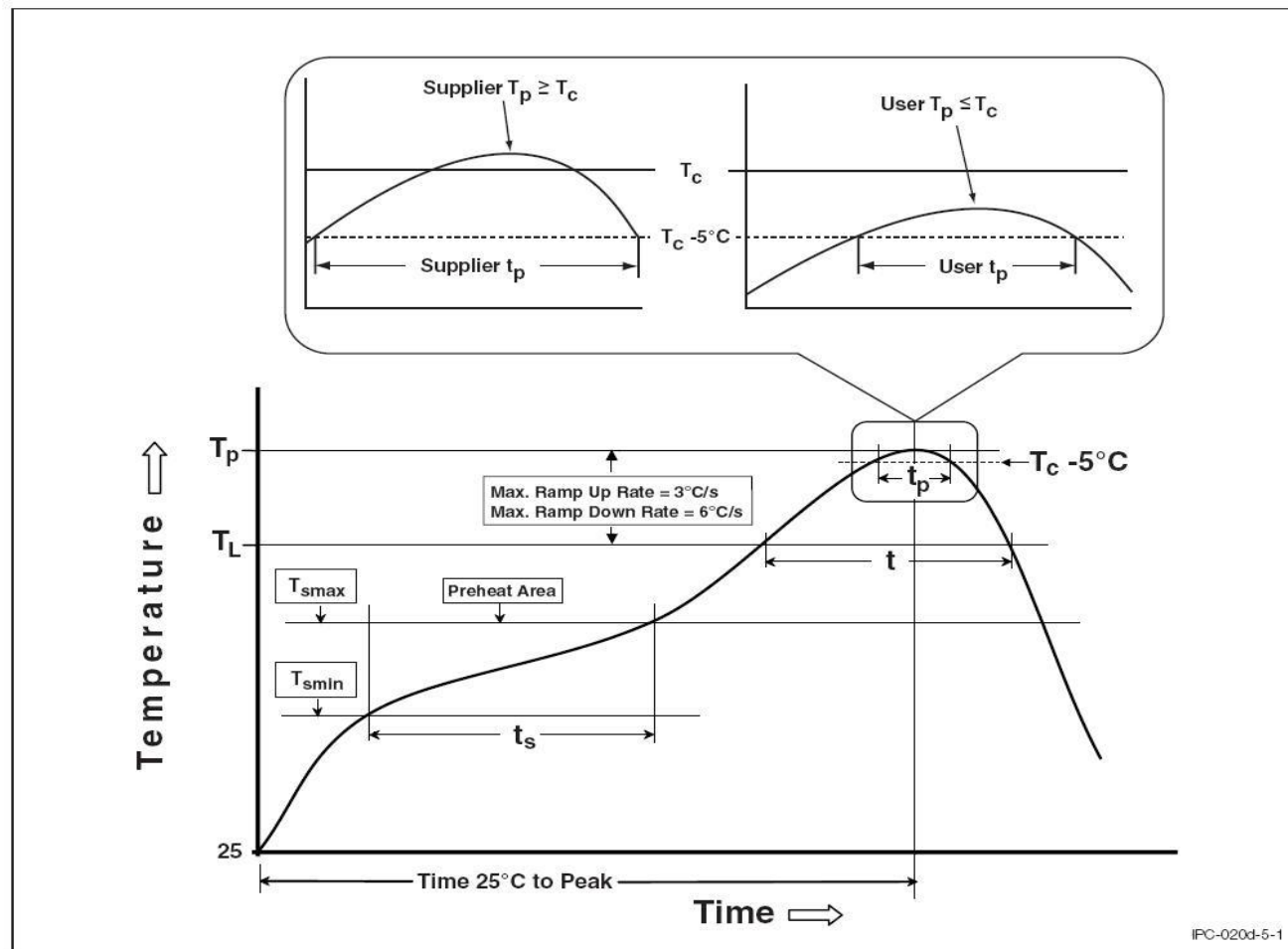
TWS – Company Abbr.
851 – Part Number
Y – Lead Form Option (M/S/SL/SLM/None)
Z – Tape and Reel Option (T1/T2/T3/T4)
G – Green

**Packing Quantity**

Option	Quantity	Quantity – Inner box	Quantity – Outer box
None	100 Units/Tube	32 Tubes/Inner box	10 Inner box/Outer box = 32k Units
M	100 Units/Tube	32 Tubes/Inner box	10 Inner box/Outer box = 32k Units
S(T1)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
S(T2)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
S(T3)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
S(T4)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
SL(T1)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
SL(T2)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
SL(T3)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
SL(T4)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
SLM(T1)	1500 Units/Reel	2 Reels/Inner box	5 Inner box/Outer box = 15k Units
SLM(T2)	1500 Units/Reel	2 Reels/Inner box	5 Inner box/Outer box = 15k Units

REFLOW INFORMATION

REFLOW PROFILE

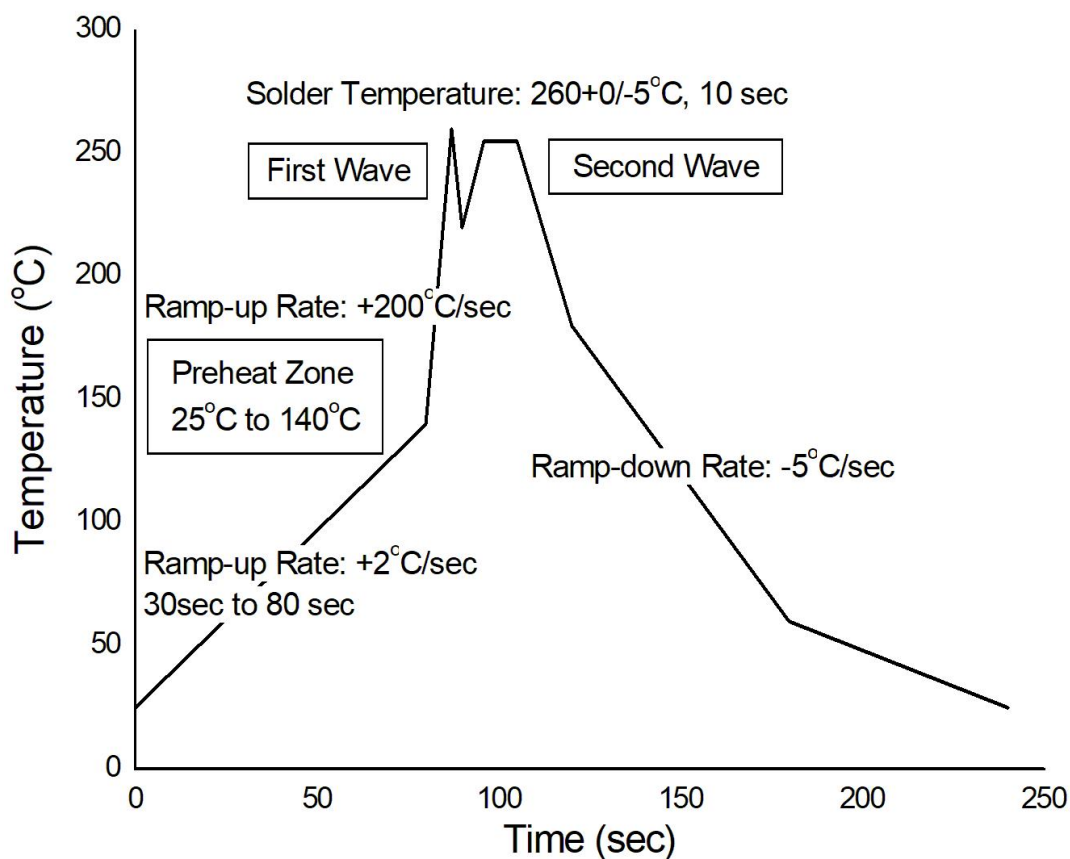


IPC-020d-5-1

Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (T _{smin})	100	150°C
Temperature Max. (T _{smax})	150	200°C
Time (t _s) from (T _{smin} to T _{smax})	60-120 seconds	60-120 seconds
Ramp-up Rate (t _L to t _P)	3°C/second max.	3°C/second max.
Liquidous Temperature (T _L)	183°C	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds	60 – 150 seconds
Peak Body Package Temperature	235°C +0°C / -5°C	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max	6°C/second max
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

TEMPERATURE PROFILE OF SOLDERING

WAVE SOLDERING (JESD22-A111 COMPLIANT)



HAND SOLDERING BY SOLDERING IRON

Soldering Temperature	$380 \pm 0/-5^{\circ}\text{C}$
Soldering Time	3 sec max.

- One time soldering is recommended for all soldering method.
- Do not solder more than three times for IR reflow soldering.

DISCLAIMER

- TWS is continually improving the quality, reliability, function and design. TWS reserves the right to make changes without further notices.
- The characteristic curves shown in this datasheet are representing typical performance which are not guaranteed.
- TWS makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, TWS disclaims (a) any and all liability arising out of the application or use of any product, (b) any and all liability, including without limitation special, consequential or incidental damages, and (c) any and all implied warranties, including warranties of fitness for particular
- The products shown in this publication are designed for the general use in electronic applications such as office automation, equipment, communications devices, audio/visual equipment, electrical application and instrumentation purpose, non-infringement and merchantability.
- This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or lifesaving applications or any other application which can result in human injury or death.
- Please contact TWS sales agent for special application request.
- Immerge unit's body in solder paste is not recommended.
- Parameters provided in datasheets may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated in each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify TWS's terms and conditions of purchase, including but not limited to the warranty expressed therein.
- Discoloration might be occurred on the package surface after soldering, reflow or long-time use. It neither impacts the performance nor reliability.